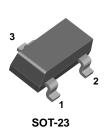
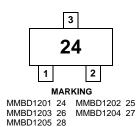
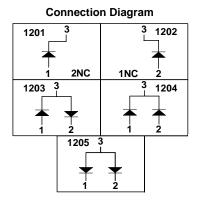


August 2011

# MMBD1201 / 1202 / 1203 / 1204 / 1205 Small Signal Diodes







# **Absolute Maximum Ratings\*** T<sub>A</sub> = 25°C unless otherwise noted

Symbol	Parameter	Value	Units	
$V_{RRM}$	Maximum Repetitive Reverse Voltage	100	V	
I <sub>F(AV)</sub>	Average Rectified Forward Current	200	mA	
I <sub>FSM</sub>	Non-repetitive Peak Forward Surge Current Pulse Width = 1.0 second Pulse Width = 1.0 microsecond	1.0 2.0	A A	
T <sub>STG</sub>	Storage Temperature Range	-55 to +150	°C	
TJ	Operating Junction Temperature	150	°C	

<sup>\*</sup>These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

## NOTES

- 1) These ratings are based on a maximum junction temperature of 150 degrees C.
- 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

# Thermal Characteristics $T_A = 25$ °C unless otherwise noted

Symbol	Parameter	Value	Units
P <sub>D</sub>	Power Dissipation	350	mW
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	357	°C/W

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# **Electrical Characteristics** $T_A = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Max.	Units
V <sub>R</sub>	Breakdown Voltage	I <sub>R</sub> = 100μA	100		V
V <sub>F</sub>	Forward Voltage	I <sub>F</sub> = 1.0mA	550	600	mV
		$I_F = 10mA$	660	740	mV
		$I_F = 100 \text{mA}$	820	920	mV
		$I_F = 200 \text{mA}$	0.87	1.0	V
		$I_F = 300 \text{mA}$	-	1.1	V
I <sub>R</sub>	Reverse Leakage	V <sub>R</sub> = 20V		25	nA
		$V_R = 50V$		50	nA
		$V_R = 50V, T_A = 150^{\circ}C$		5.0	μΑ
C <sub>T</sub>	Total Capacitance	$V_R = 0, f = 1.0MHz$		2.0	pF
t <sub>rr</sub>	Reverse Recovery Time	$I_F = I_R = 10$ mA, $I_{RR} = 1.0$ mA $R_L = 100$ $\Omega$		4.0	ns

# **Typical Performance Characteristics**

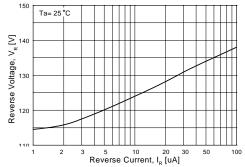


Figure 1. Reverse Voltage vs Reverse Current BV - 1.0 to 100uA

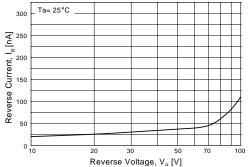


Figure 2. Reverse Current vs Reverse Voltage IR - 10 to 100 V

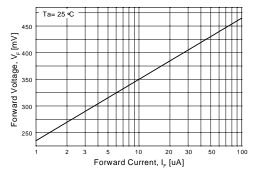


Figure 3. Forward Voltage vs Forward Current VF - 1.0 to 100 uA

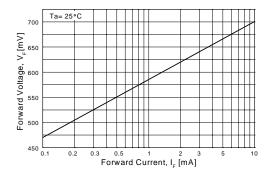


Figure 4. Forward Voltage vs Forward Current VF - 0.1 to 10 mA

# **Typical Performance Characteristics** (Continued)

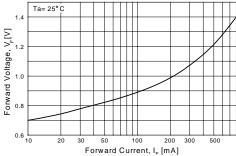


Figure 5. Forward Voltage vs Forward Current VF - 10 - 800 mA

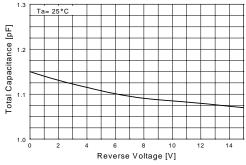


Figure 6. Total Capacitance vs Reverse Voltage

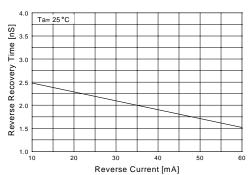


Figure 7. Reverse Recovery Time
vs Reverse Current
TRR - IR 10 mA vs 60 mA

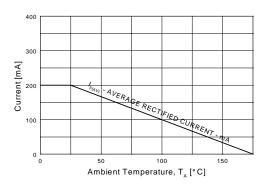


Figure 8. Average Rectified Current  $(I_{F(AV)})$  versus Ambient Temperature  $(T_{A})$ 

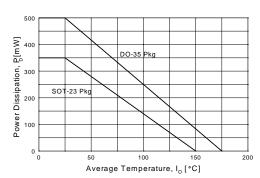


Figure 9. Power Derating Curve





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